WeEn

NXPSC20650W

Silicon Carbide Diode

Rev.03 - 06 May 2020

Product data sheet

1. General description

Dual Silicon Carbide Schottky diode in a 3-lead TO247 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- Highly stable switching performance
- High forward surge capability I_{FSM}
- Extremely fast reverse recovery time
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- Reduced cooling requirements
- RoHS compliant

3. Applications

- Power factor correction
 - Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Q	uick reference data						
Symbol	Parameter	Conditions	Values			Unit	
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage		650			V	
I _{O(AV)}	average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 105 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	20		А		
T _j	junction temperature		175		°C		
Symbol	Parameter	Conditions	Min Typ Max		Unit		
Static ch	aracteristics						
V _F	forward voltage	$I_F = 10 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.5	1.7	V
		$I_F = 10 \text{ A}; T_j = 150 \text{ °C}; \text{ per diode}; Fig. 5$		-	1.8	2.1	V
Dynamic	characteristics						
Q _r	recovered charge	$I_F = 10 \text{ A}; dI_F/\text{d}t = 500 A/\mu\text{s}; V_R = 400 \text{ V}; \\ T_j = 25 ^\circ\text{C}; \text{ per diode}; \underline{\text{Fig. } 7}$		-	16	-	nC

5. Pinning information

Table 2. P	inning infor	mation		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	К	cathode		
3	A2	anode		<u> </u>
mb	mb	mounting base; connected to cathode		sym125

6. Ordering information

Table 3. Ordering information								
Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date		
NXPSC20650W	TO247	NXPSC20650W6Q	Tube	30	TO247N	20-July-2016		

7. Marking

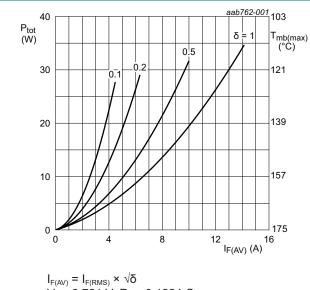
Table 4. Marking codes						
Type number	Marking codes					
NXPSC20650W	NXPSC 20650W					

8. Limiting values

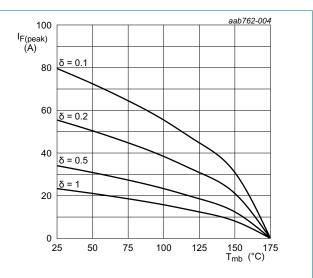
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V _{RRM}	repetitive peak reverse voltage		650	V
V _{RWM}	crest working reverse voltage		650	V
V _R	reverse voltage	DC	650	V
I _{O(AV)}	average forward current	δ = 0.5; square-wave pulse; T _{mb} ≤ 105 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	20	A
I _{FRM}	repetitive peak forward current	δ = 0.5; t _p = 25 µs; T _{mb} ≤ 112 °C; square-wave pulse; per diode	20	A
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	50	A
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode	450	A
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)}$ = 25 °C; t_p = 10 ms	12.5	A ² s
T _{stg}	storage temperature		-55 to 175	°C
Tj	junction temperature		175	°C

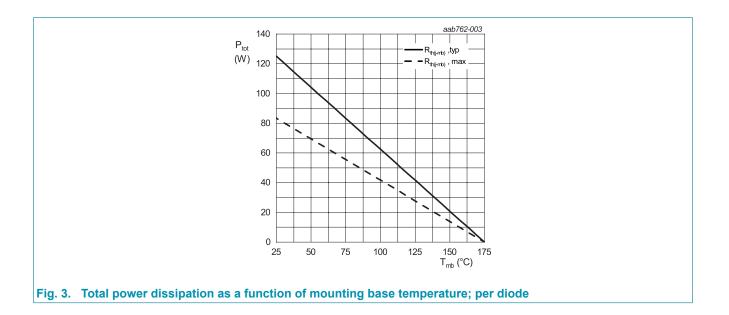


I_{F(AV)} = I_{F(RMS)} × √δ
V_o = 0.721 V; R_s = 0.1224 Ω
Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode



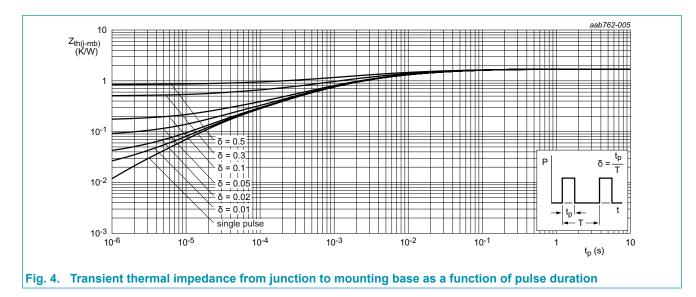


NXPSC20650W Silicon Carbide Diode



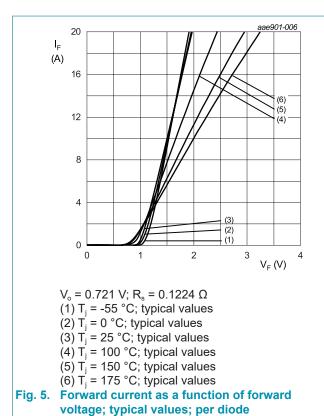
9. Thermal characteristics

Table 6. Th	ermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
$R_{\text{th(j-mb)}}$	thermal resistance	per diode; <u>Fig. 4</u>	-	1.2	1.8	K/W
	from junction to mounting base	both diodes conducting	-	-	1	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	45	-	K/W



10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
	aracteristics					
V_{F}	forward current	$I_{F} = 10 \text{ A}; T_{j} = 25 \text{ °C}; \text{ per diode}; Fig. 5$	-	1.5	1.7	V
		I _F = 10 A; T _j = 150 °C; per diode; <u>Fig. 5</u>	-	1.8	2.1	V
I _R	reverse current	V_{R} = 650 V; T _j = 25 °C; per diode; <u>Fig. 6</u>	-	-	60	μA
		V_{R} = 650 V; T _j = 150 °C; per diode; <u>Fig. 6</u>	-	-	240	μA
Dynamic	characteristics					,
Q _r	recovered charge	I _F = 10 A; V _R = 400 V; dI _F /dt = 500 A/μs; T _i = 25 °C; per diode; <u>Fig. 7</u>	-	16	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	328	-	pF
		f = 1 MHz; V _R = 300 V; T _j = 25 °C	-	44	-	pF
		f = 1 MHz; V _R = 600 V; T _j = 25 °C	-	42	-	pF
E _{as}	non-repetitive avalanche energy	$I_R = 5.5 \text{ A}; \text{ L} = 5 \text{ mH}; \text{ T}_{j(init)} = 25 \text{ °C};$ per diode	75	-	-	mJ



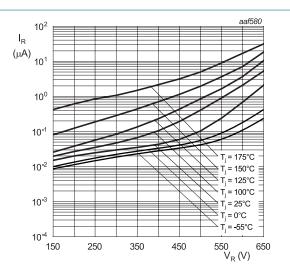
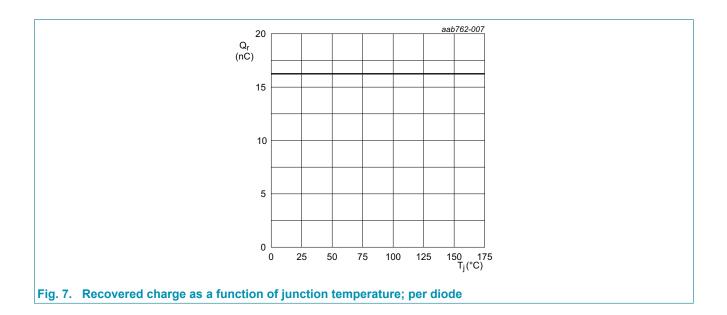
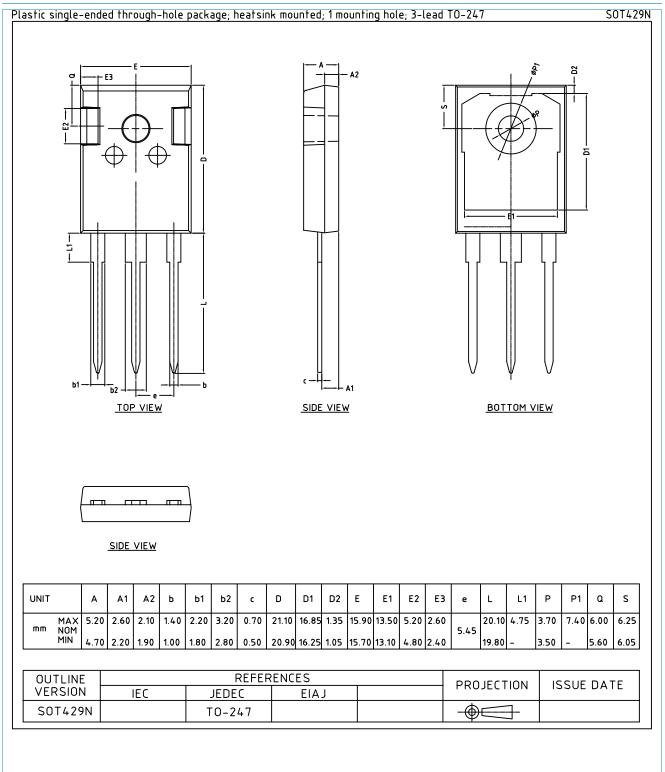


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value; per diode

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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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